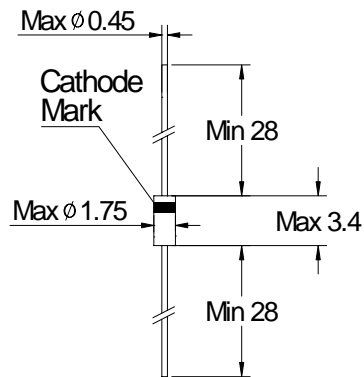


# 1N4148-K

## SILICON EPITAXIAL PLANAR DIODE

Fast switching diode

This diode is also available in MiniMELF case with the type designation LL4148.

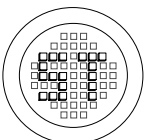


Glass case DO-35  
Dimensions in mm

### Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

	Symbol	Value	Unit
Reverse Voltage	$V_R$	75	V
Peak Reverse Voltage	$V_{RM}$	100	V
Rectified Current (Average) Half Wave Rectification with Resist. Load at $T_{amb} = 25^\circ\text{C}$ and $f \geq 50 \text{ Hz}$	$I_O$	150 <sup>1)</sup>	mA
Surge Forward Current at $t < 1 \text{ s}$ and $T_j = 25^\circ\text{C}$	$I_{FSM}$	500	mA
Power Dissipation	$P_{tot}$	500 <sup>1)</sup>	mW
Junction Temperature	$T_j$	200	$^\circ\text{C}$
Storage Temperature Range	$T_S$	-65 to +200	$^\circ\text{C}$

<sup>1)</sup> Valid provided that leads at a distance of 8 mm from case are kept at ambient temperature.



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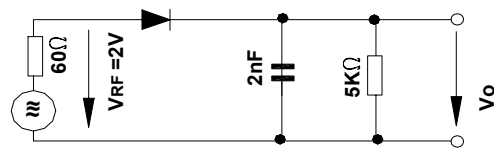
РАДИОТЕХ-ТРЕЙД

Тел.: (495) 795-0805  
Факс: (495) 234-1603  
Эл. почта: info@rct.ru  
Веб: www.rct.ru

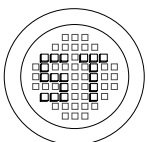
# 1N4148-K

## Characteristics at $T_j = 25^\circ\text{C}$

	Symbol	Min.	Typ.	Max.	Unit
Forward Voltage at $I_F = 10\text{mA}$	$V_F$	-	-	1	V
Leakage Current at $V_R = 20\text{V}$ at $V_R = 75\text{V}$ at $V_R = 20\text{V}, T_j = 150^\circ\text{C}$	$I_R$ $I_R$ $I_R$	- - -	- - -	200 5 50	nA $\mu\text{A}$ $\mu\text{A}$
Reverse Breakdown Voltage at $I_R = 100\mu\text{A}$ at $I_R = 5\mu\text{A}$	$V_{(BR)R}$ $V_{(BR)R}$	100 75	- -	- -	V V
Capacitance at $V_F = V_R = 0$	$C_{\text{tot}}$	-	-	4	pF
Voltage Rise when Switching ON tested with 50 mA Forward Pulses $t_p = 0.1\text{ s}$ , Rise Time < 30ns, $f_p = 5\text{ to }100\text{ kHz}$	$V_{\text{fr}}$	-	-	2.5	V
Reverse Recovery Time from $I_F = 10\text{mA}$ to $I_R = 1\text{mA}$ , $V_R = 6\text{V}$ , $R_L = 100\Omega$	$t_{\text{rr}}$	-	-	4	ns
Thermal Resistance Junction to Ambient Air	$R_{\text{thA}}$	-	-	0.35 <sup>1)</sup>	K/mW
Rectification Efficiency at $f = 100\text{MHz}$ , $V_{\text{RF}} = 2\text{V}$	$\eta_v$	0.45	-	-	-
<sup>1)</sup> Valid provided that leads at a distance of 8 mm from case are kept at ambient temperature.					

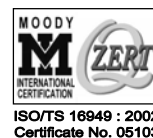


Rectification Efficiency Measurement Circuit



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ISO/TS 16949 : 2002  
Certificate No. 05103



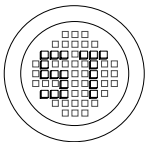
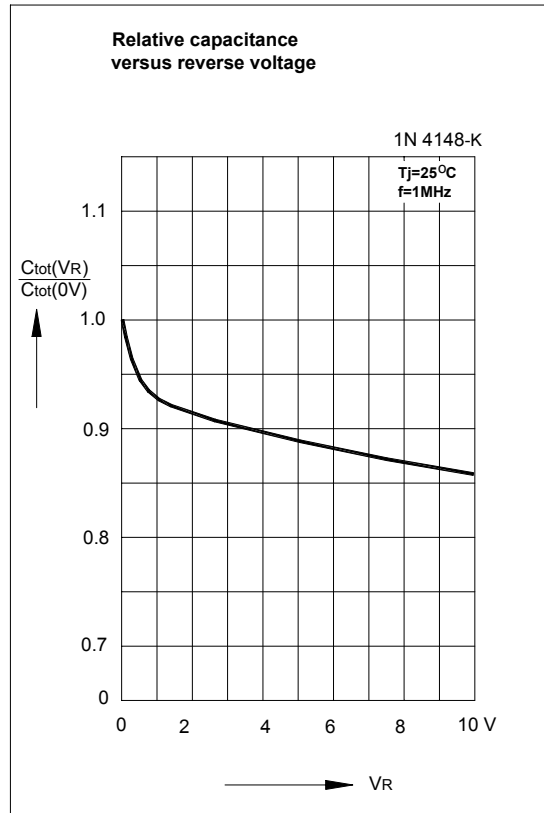
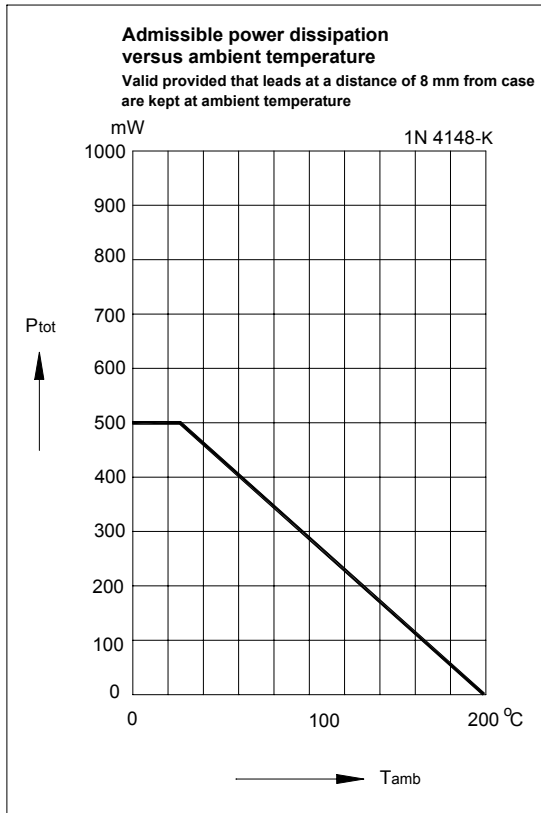
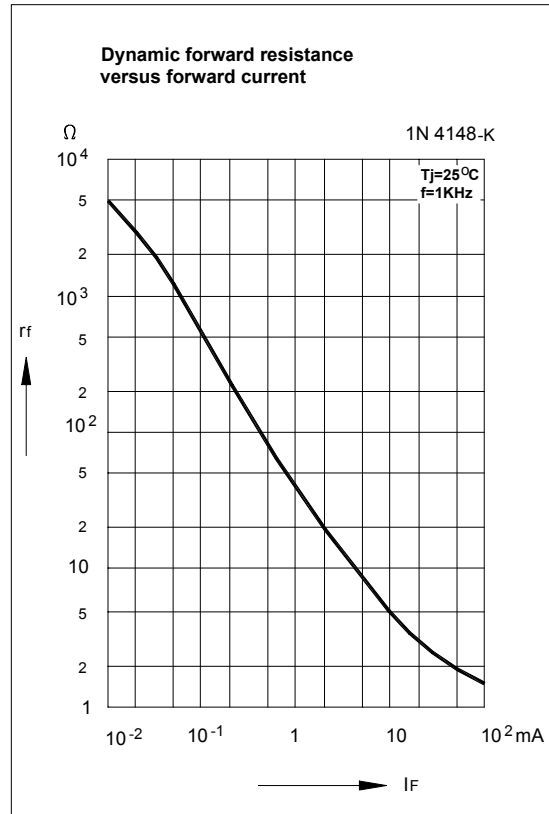
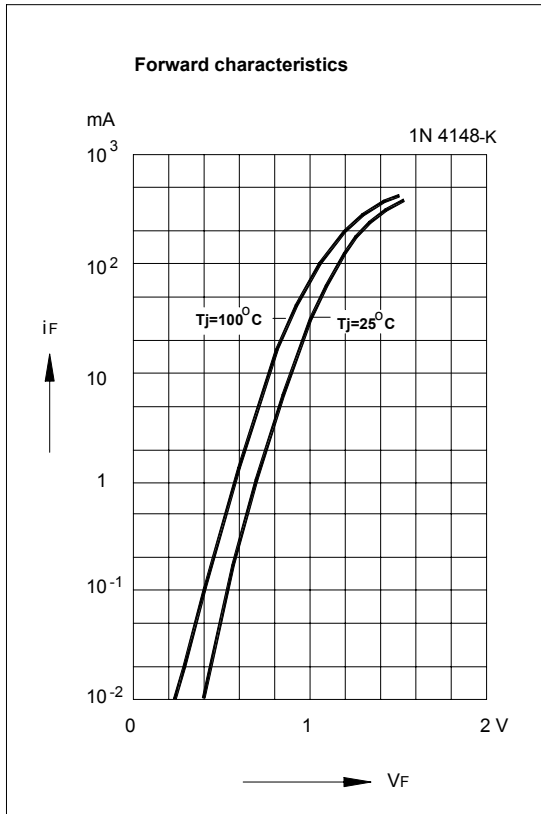
ISO 14001  
Certificate No. 7116



ISO 9001 : 2000  
Certificate No. 550-1996-A2-R02-REV

Dated : 14/10/2005

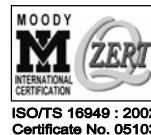
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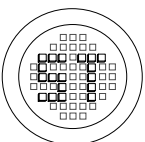
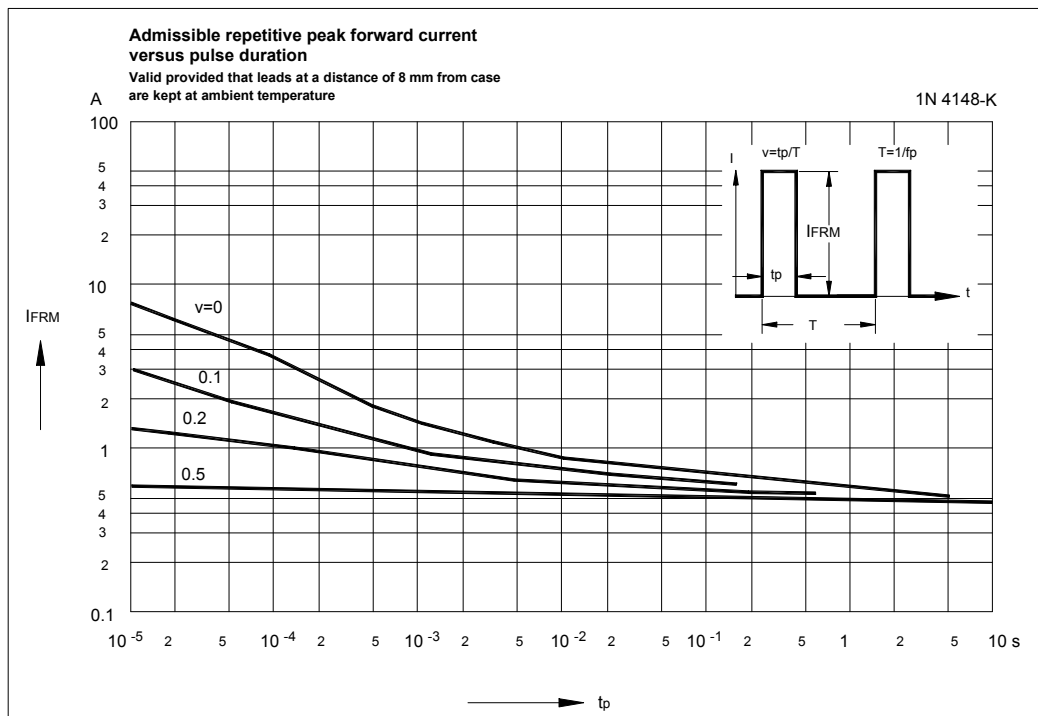
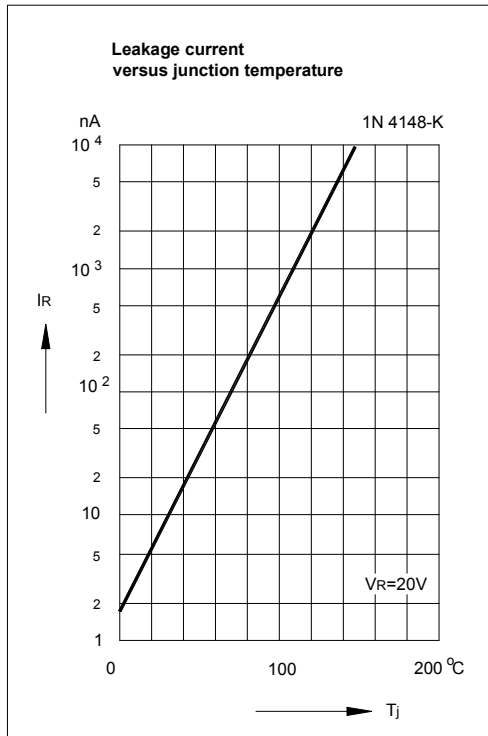
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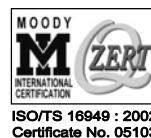
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